Polarized resonant inelastic x-ray scattering as an ultra-fine probe of excited states in La_2CuO_4

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X-ray absorption is the standard method to probe the unoccupied density of states at a given edge. Here we show that polarized Resonant Inelastic X-Ray Scattering in La_2CuO_4 at the Cu K-edge is extremely sensitive to the environment of the Cu atom and the fine structure in the Cu 4p density of states. Combined *ab initio* and many-body cluster calculations, used for the first time in such a context, show remarkable agreement with experiment. In particular we identify a non-local effect namely a transition to *off-site* Cu 3d states.

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X-ray absorption spectroscopy (XAS) has long been used to investigate the nature of the partial density of excited states at a given absorption threshold. However pre-edge features, mainly composed of quadrupolar excitations, are often hard to detect in XAS due to their small intensity and the broadening due to the core-hole lifetime. As a consequence important insights related to the local environment of the absorbing atom are not accessible in XAS. Here we show that resonant inelastic X-ray scattering (RIXS) yields a precise determination of the low-energy unoccupied electronic states and the chemical environment of the absorbing atom. RIXS is a powerful tool for the study of the electronic excitations in solids[1] giving access to site, element and orbital selective information. It is a second order process where the X-ray emission is measured as the incident X-ray energy is tuned through an absorption edge of the sample. The incident energy determines the intermediate state and the core-hole enhances the cross section [2].

In this work we study resonant Cu 1s-2p emission in La_2CuO_4 both from an experimental and theoretical point of view. The excited states in La_2CuO_4 are of interest because of the correlated nature of this compound which on hole doping becomes a high temperature superconductor. The hopping between the Cu $3d_{x^2-y^2}$ and the O 2p orbitals combined with Coulomb repulsion between Cu 3d electrons form the basis for describing the low energy excitations in this solid [3]. In the intermediate state of the resonant process a 1s Cu core-electron is excited to states with energies around the pre-edge region of the Cu K-absorption edge. The final state involves $K\alpha$ emission with filling of the 1s hole at the expense of a hole in the 2p state. Identifying the measured features and explaining their dependence on incident energy and incident photon polarisation is not a trivial task from the theoretical point of view, particularly in strongly correlated systems where single particle theories like standard density functional theory (DFT) dramatically fail due to the lack of important many-body effects. A different approach to the problem is the use of many-body cluster models based on multiband Hubbard-like hamiltonian. While these methods correctly include many-body effects they often require some knowledge of the empty state density of states (DOS) which cannot be easily obtained without the use of *ab initio* electronic structure calculations. For this reason core level spectroscopy is an ideal field for the application of combined *ab initio* and many-body cluster model approaches.

The orthorhombic structure of La₂CuO₄ with the CuO planes oriented perpendicular to the c-axis allows the incident X-ray polarization to be unequivocally defined. Our twinned La₂CuO₄ single crystal was a plate-like rectangular sample with the c-axis perpendicular to the sample plane and the a/b axis parallel to the sides of the sample. The experiment was performed at beamline ID16 at the European Synchrotron Radiation Facility. The experimental setup was that of a Rowland circle spectrometer with a horizontal scattering plane, using a spherically focusing, bent Si(444) analyzer [4]. The absorption spectrum of La₂CuO₄ was obtained by measuring the total fluorescence yield. We also measured the partial fluorescence yield spectrum by using the spectrometer set to the peak of the $K\alpha_1$ fluorescence line and varying the incident energy as for an absorption measurement. These were measured for two orientations of the sample: In the first geometry (noted a/b henceforth) the a-b plane was in the horizontal scattering plane such that it contained both the incident photon momentum and the polarization. They were both oriented at 45° with respect to the a/b axis. In the second geometry (noted c)

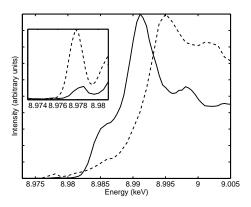


FIG. 1: Partial fluorescence yield absorption spectra for La₂CuO₄ in the a-b geometry (dashed line) showing transitions to Cu $4p_{\sigma}$ orbitals and the c geometry (solid line) showing transitions to Cu $4p_{\pi}$ orbitals. Each spectrum is normalized to its peak. The inset is a zoom of the pre-edge area where resonant scans are taken.

the a-b plane, oriented vertically, was perpendicular to the scattering plane. The polarization was at 75° with respect to the a-b plane $(15^{\circ} \text{ with respect to the c-axis})$ of the sample). These geometries were also used for the measurement of the 1s2p resonant emission. It should be noted that due to the in-plane polarization of the photons the a/b geometry is sensitive to the in-plane or σ orbitals only while the c geometry is sensitive primarily to the π orbitals. The absorption spectrum is characterized by a small pre-peak at the onset, usually attributed at least partly to on-site Cu 1s-3d quadrupolar transitions. In Fig. 1 we show the partial fluorescence yield spectra for both geometries. In our RIXS measurements the incident energy is limited to the region around the pre-peak (inset of Fig. 1 and left panels of Fig. 2 and Fig. 3). It will be seen that the dipolar contribution in this pre-edge region being small, the weak on-site Cu 1s-3d quadrupolar transition is easily visible. Most importantly we will show that an even weaker off-site Cu 1s-3d dipolar transition mediated by O2p states and never before identified is also clearly visible in the RIXS spectra. Though the absorption spectrum is relatively featureless, the emission spectra are rich in structure and strongly dependent on the incident energy.

In Fig. 2 and Fig. 3 (center panels) we show the experimental RIXS spectra for incident energies increasing from bottom up. The baseline of each RIXS spectrum corresponds to the incident energy at which it was measured as seen on the absorption spectrum on the left panel. RIXS spectra have been arbitrarily shifted such that the lowest energy transfer feature corresponds to the zero of the energy scale and have been normalized to the most intense feature in each spectrum. They show twin features separated by 20 eV due to spin-orbit splitting of the 2p core level. In the following we shall discuss only the region from 0 eV to -20eV energy transfer. The spectra

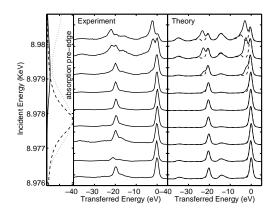


FIG. 2: a/b geometry. Left panel: The pre-edge region of the absorption spectrum. Experiment (dotted line), clustermodel calculated *on-site* Cu 1s-3d quadrupolar (dashed line) and *off-site* Cu 1s-3d dipolar contributions (solid line). Center panel: Measured RIXS spectra. The incident energy can be traced to the absorption curve in the left panel. Right panel: Calculated RIXS spectra using *ab initio* Cu 4p DOS (solid line) and the modified DOS shown in the inset of Fig. 4 (dashed line). The peak at 0 eV is due to the *on-site* Cu 1s-3d transition. The additional peak appearing at -3 eV in the RIXS spectra is due to the lowest energy feature of the $4p_{\sigma}$ DOS which is determined by the hybridization with *off-site* Cu 3d empty states.

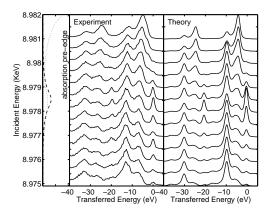


FIG. 3: *c* geometry. Left panel: The pre-edge region of the absorption spectrum. Experiment (dotted line), calculated *on-site* Cu 1s-3d quadrupolar contribution (dashed line). Center panel: Measured RIXS spectra. The incident energy can be traced to the absorption curve in the left panel. Right panel: Calculated RIXS spectra.

are dominated by a sharp peak at 0 eV which resonates when excitation energies are on the absorption pre-peak. In CuO a similar structure has been interpreted as due to a quadrupolar transition [18, 19]. By separately calculating the contribution of $1s \rightarrow 3d$ quadrupolar, and $1s \rightarrow 4p_{\sigma}$ and $1s \rightarrow 4p_{\pi}$ dipolar transitions we easily confirm that in La₂CuO₄ this peak is due to the quadrupolar transition. In both geometries two additional features are seen. In the a/b geometry (Fig. 2) a weak, broad, peak is observed around -17 eV while a sharp peak at about -3 eV resonates only at higher incident energies. In the c geometry (Fig. 3) a strong broad structure with twin peaks at -12 eV and -7 eV is seen while a second peak appears at -5 eV, resonating at higher incident energies. The calculated results of the Cu K α RIXS are shown in Fig. 2 and Fig. 3 (right panels) and are in excellent agreement with the experimental ones. The broad structures at higher energy loss are attributed to virtual transitions due to the main peaks in the Cu 4p DOS and are slightly shifted in energy from the measured ones. The lower energy resonant structures are due to transitions to features in the tails of the DOS. These attributions were made by modifying portions of the calculated RIXS spectrum.

RIXS data are interpreted using a unified *ab initio* and multiplet calculations approach. Numerical multiplet calculations were carried out based on CuO_6^{10-} single cluster model with intra-atomic full multiplets in D_{4h} local symmetry and including the screening channel for charge transfer from O 2p ligand state. Only a single Cu atom is retained and charge transfer between the Cu 3d state and the neighboring O 2p orbitals is allowed. The Hamiltonian is given by $H = H_0 + H_{pd} + H_{ch} + H_{\text{multiplet}}$. H_0 includes the on-site energies of the Cu 1s (ε_{1s}), Cu 2p (ε_{2p}), Cu 3d ($\varepsilon_{3d}(\Gamma)$), Cu 4p ($\varepsilon_{4p}(k)$) and Ligand O 2p ($\varepsilon_p(\Gamma)$) states; $H_0 = \sum_{\Gamma,\sigma} \varepsilon_{3d}(\Gamma) d^{\dagger}_{\Gamma\sigma} d_{\Gamma\sigma} +$ $\sum_{m,\sigma} \varepsilon_{2p} p_{m\sigma}^{\dagger} p_{m\sigma} + \sum_{\sigma} \varepsilon_{1s} s_{\sigma}^{\dagger} s_{\sigma} + \sum_{k,\sigma} \varepsilon_{4p}(k) P_{k\sigma}^{\dagger} P_{k\sigma} +$ $\sum_{\Gamma,\sigma} \varepsilon_p(\Gamma) a^{\dagger}_{\Gamma\sigma} a_{\Gamma\sigma}$. The irreducible representations of the D_{4h} symmetry are Γ ($= b_{1g}, a_{1g}, b_{2g}$ and e_g). H_{pd} is the hybridization between Cu 3d and O 2p ligand states, $H_{pd} = \sum_{\Gamma,\sigma} V(\Gamma) (d^{\dagger}_{\Gamma\sigma} a_{\Gamma\sigma} + a^{\dagger}_{\Gamma\sigma} d_{\Gamma\sigma})$. The corehole interaction H_{dc} is composed of two contributions, the attraction between Cu 3d electrons and Cu 1s holes $(U_{dc}(1s))$ and between Cu 3d electrons and Cu 2p holes, $(U_{dc}(2p))$, namely $H_{dc} = U_{dc}(1s) \sum_{\Gamma,\sigma,\sigma'} d^{\dagger}_{\Gamma\sigma} d_{\Gamma\sigma} (1 - C_{dc}(1s))$ $s_{\sigma'}^{\dagger}s_{\sigma'}) + U_{dc}(2p) \sum_{\Gamma,m,\sigma,\sigma'} d_{\Gamma\sigma}^{\dagger} d_{\Gamma\sigma} (1 - p_{m\sigma'}^{\dagger} p_{m\sigma'}).$ Finally the Hamiltonian $H_{\text{multiplet}}$ describes the intra-atomic multiplet coupling originating from the multipole components of the Coulomb interaction between Cu 3d states and that between Cu 3d and 2p or 1s states and the spinorbit interactions for Cu 3d and 2p states [5, 6, 7, 8].

The parameter values used are (in eV): $U_{dc}(1s) = U_{dc}(2p) = -7.0$, $V(b_{1g}) = 2.5$, $V(a_{1g}) = 1.44$, $V(b_{2g}) = 1.25$, $V(e_g) = 0.88$, $\Delta = 2.75$ (charge transfer energy), $T_{pp} = 1.0$ (hybridization between nearest neighbor O 2p orbitals), very close to the ones used in ref. [6]. The Slater integrals and the spin-orbit coupling constants are calculated by Cowan's Hartree-Fock program, [5] and then the Slater integrals are scaled down to 80%.

The K α RIXS cross-section is calculated on the basis of the formula of the coherent second order optical process as $S(\Omega, \omega) = S_D(\Omega, \omega) + S_Q(\Omega, \omega)$ where $S_\alpha(\Omega, \omega)$ with $\alpha = D, Q$ is:

$$S_{\alpha}(\Omega,\omega) = \sum_{f} \left| \sum_{m} \frac{\langle f \mid T_{D} \mid m \rangle \langle m \mid T_{\alpha} \mid g \rangle}{E_{g} + \Omega - E_{m} - i\Gamma_{K}} \right|^{2} \\ \times \frac{\Gamma_{L}/\pi}{(E_{g} + \Omega - E_{f} - \omega)^{2} + \Gamma_{L}^{2}} , \qquad (1)$$

and $|g\rangle$, $|m\rangle$ and $|f\rangle$ are the ground, intermediate and final states of the Hamiltonian H with energies E_g, E_m and E_f , respectively. The incident and emitted photon energies are represented by Ω and ω , respectively. The core-hole lifetime broadening is denoted by $\Gamma_K = 0.4 \text{ eV}$, half width at half maximum (HWHM) for the 1s corehole and $\Gamma_L = 0.2 \text{ eV}$ (HWHM) for the 2p core-hole. Gaussian broadening due to the experimental resolution is taken to be 0.6 eV (HWHM). The operators T_{α} with $\alpha = D, Q$ represent the optical dipole and quadrupole transition respectively. The polarization of the incident photon is also taken into account [7, 8].

To calculate eq. 1, we use, as basis states, two configurations, $3d^9$ and $3d^{10}\underline{L}$, where \underline{L} represents a hole in the ligand states. The basis configurations in the intermediate state $\mid m \rangle$ are $\underline{1s}3d^{10}\underline{L}4p$ for the quadrupole transition and $\underline{1s}3d^94p$ and $\underline{1s}3d^{10}\underline{L}4p$ for the dipole excitation. The final states $\mid f \rangle$ are $\underline{2p}3d^{10}$ (quadrupole) and $\underline{2p}3d^94p$ and $\underline{2p}3d^{10}\underline{L}4p$ (dipole). In the case of dipolar transitions we assume the intermediate states $\mid m \rangle$ (final states $\mid f \rangle$) to be a direct product of a Cu 4p state $\mid k \rangle$ and the remaining system $\mid m' \rangle$ ($\mid f' \rangle = \mid k \rangle \mid m' \rangle$) with energies $E_m = E_{m'} + \varepsilon_k$ ($E_f = E_{f'} + \varepsilon_k$). Thus we can transform the sum over m in eq. 1 to a sum over m' plus an integral over the high enenergy continuum weighted over the 4p Cu projected density of states $\rho_{\eta}(\epsilon)$ (with $\eta = \sigma, \pi$), namely: $\sum_m \longmapsto \sum_{m'} \int d\epsilon \rho_{\eta}(\epsilon) [8]$. The Cu 4p projected density of states, $\rho_{\eta}(\epsilon) =$

 $\frac{1}{N_k}\sum_i\sum_{kn}|\langle \psi|\tilde{\mathbf{Cu}}^{\dagger}\tilde{4}p_{\eta}\rangle|^2\delta(\epsilon_{\mathbf{k}n}-\epsilon), \text{ is calculated } ab$ *initio*[9] using the Kohn-Sham eigenvalues $(\epsilon_{\mathbf{k}n})$ and eigenfunctions $(\psi_{\mathbf{k}n})$ and the $|\mathrm{Cu}^{\mathrm{i}}4p_n\rangle$ orthonormalized atomic orbitals. We disregard the core hole potential acting on the 4p state, because it is screened strongly by a 3d electron transferred from the O 2p states. Since we consider a supercell with two La₂CuO₄ molecules, ρ_n is also summed over the two inequivalent Cu atoms (i = 1, 2). In the *ab initio* simulations we use ultrasoft pseudopotentials [10] with a 45 Ry cutoff and the spin-polarized generalized gradient approximation (SPGGA) [11] for the exchange-correlation kernel. Since using the SPGGA the ground state turns out to be metallic we adopted the SPGGA+U approximation [12] with $U = 8 \,\mathrm{eV}$ in the implementation of ref. [13]. Self-consistence is performed over a $6 \times 6 \times 6$ k-points mesh in the Brillouin zone centered at the Γ point. We converge to an antiferromagnetic state with Cu local magnetic moment $0.625\mu_B$, to be compared with the experimental value of $0.55 \sim 0.60 \mu_B$ [14, 15]. The band gap is approximately 0.65 eV, in good agreement with previous calculations of

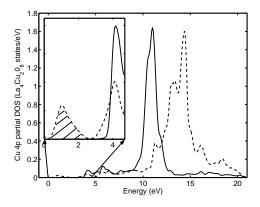


FIG. 4: Projected Cu $4p_{\pi}$ (solid) and $4p_{\sigma}$ (dashed line) orbital density of states calculated *ab initio*. The inset shows the low energy region in detail. The hatched peak, the lowest energy structure in the Cu $4p_{\sigma}$ DOS, is induced by hydridization between the Cu $4p_{x,y}$ atomic orbitals, the empty O 2p orbitals and the empty 3d orbitals of the neighbouring Cu atoms forming a b_{1g} state.

ref. [16] (0.7 eV), but substantially smaller than the one determined from optical conductivity data in ref. [17] ($\approx 2 \text{ eV}$). The Cu $4p_{\sigma,\pi}$ projected DOS calculated on a $N_k = 20 \times 20 \times 20$ k-points mesh are shown in Fig. 4.

For a finer comparison between theory and experiment let us first consider the sharp peak at 0 eV in Fig. 2 and Fig. 3 due to the on-site 1s-3d quadrupolar excitations, where the intermediate state is $\underline{1s}3d^{10}$ and the final state is $2p3d^{10}$. The $2p3d^{10}$ final state shows no multiplet structure because the 3d shell is filled, which explains the single peak spectral shape. Next, we consider the dipolar contribution. In the a/b geometry the polarization being in the a-b plane, only $1s \rightarrow 4p_{\sigma}$ transitions contribute. In the c geometry π transitions are visible, the σ component being almost negligible (see Fig. 3). Finally we illustrate the extreme sensitivity of this method by looking for the origin of the peak at -3 eV in the a/b geometry. A closer look at the Cu 4p DOS in Fig. 4 reveals that though the main peak of the σ component is at higher energy than that of the π component, the lowest energy structure is σ in nature. The intensity of this structure, peaking at 1eV, is less than one percent of the total DOS in this region. Nevertheless if this structure is artificially truncated (indicated by the hatching in Fig. 4), the peak at -3 eV disappears in the calculated RIXS (Fig. 2, right panel, dashed curve). This low energy structure in the Cu $4p_{\sigma}$ DOS is induced by the hybridization with O 2p states and with the Cu 3d b_{1q} empty state of the neighbouring Cu sites. This is the first identification of this 1s-3d offsite transition mediated by the O 2p orbitals and shows the chemical detail which such a measurement reveals. It is also present in the calculated absorption in the a/b geometry (Fig. 2, left panel) while absent in the calculated absorption in the c geometry (Fig. 3, left panel) and in the measured and calculated RIXS (Fig. 3, center and right panels)

XANES measurements have long been the standard method for accessing excited states. Earlier works [19, 20] have pointed to the advantages of RIXS. We have conclusively shown with the example of La_2CuO_4 that RIXS at the Cu K α line provides a sensitive and precise way to determine the Cu 4p unoccupied DOS and the interactions of the Cu atom with its immediate environment. We distinguish between the dipolar and quadrupolar part of the transitions and separate them according to their symmetry. We also find that a new approach combining *ab initio* calculations of the partial Cu-4p DOS with many body cluster calculations is very successful in explaining the data. Indeed both the polarization and incident energy dependance of the spectra are fully explained. Features in the measured spectra are traced to fine details of the calculated Cu-4p DOS (used directly) giving a very sensitive method for checking its reliability and identifying for the first time the off-site Cu 1s-3d dipolar transition. In particular this work, by validating the nature of the Cu 4p unoccupied DOS, will lead to the definitive attribution of the origin of the different features in the Cu K-edge X-ray absorption spectrum [21, 22]. Finally this method should prove useful for investigating the change in these excited states produced by doping as well as those induced by changes in local symmetry, notably those between the Lanthanum based hole-doped compounds and Neodymium based electron doped compounds. M.C. acknowledges discussions with G. A. Sawatzky. This work benefitted from CNRS/JSPS research grant No. 16030. Calculations were performed at the IDRIS supercomputing center (grant no. 051202). SWC was supported by the NSF-DMR-0405682.

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